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23117 7590 09/02/2008 NIXON & VANDERHYE, PC 901 NORTH GLEBE ROAD, 11TH FLOOR			EXAMINER	
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

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BEFORE THE BOARD OF PATENT APPEALS AND INTERFERENCES

Application Number: 10/577,938

Filing Date: May 03, 2006 Appellant(s): PHILLIPS ET AL.

> Stanley C. Spooner Reg. No. 27,393 For Appellant

EXAMINER'S ANSWER

This is in response to the appeal brief filed 6/9/2008 appealing from the Office action mailed 12/29/2007.

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(1) Real Party in Interest

A statement identifying by name the real party in interest is contained in the brief.

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(2) Related Appeals and Interferences

The examiner is not aware of any related appeals, interferences, or judicial proceedings which will directly affect or be directly affected by or have a bearing on the Board's decision in the pending appeal.

(3) Status of Claims

The statement of the status of claims contained in the brief is correct.

(4) Status of Amendments After Final

No amendment after final has been filed.

(5) Summary of Claimed Subject Matter

The summary of claimed subject matter contained in the brief is correct.

(6) Grounds of Rejection to be Reviewed on Appeal

The appellant's statement of the grounds of rejection to be reviewed on appeal is correct.

(7) Claims Appendix

The copy of the appealed claims contained in the Appendix to the brief is correct.

(8) Evidence Relied Upon

WO 03/081674 A1 Phillips 10-2003

WO 01/93337 A1 Phillips 12-2001

(9) Grounds of Rejection

The following ground(s) of rejection are applicable to the appealed claims:

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1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form

the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in

the United States.

2. Claims 1 to 9, 12 to 14 and 16 are rejected under 35 U.S.C. 102(b) as being

anticipated by Phillips (WO 03/081674 and hereinafter Phillips '674).

Phillips '674 show all aspects of the instant invention (e.g. Figure 4) including a

quantum-well FET with a narrow bandgap region 22 made of InSb, with two further

layers 21,23 on each side subjection said narrow bandgap region providing

compressive mechanical strain and primary/secondary conduction channels, being

no more than 0.4 eV and a layer of p-type material (Page 10 Lines 21 and 22) and

partly intrinsic conduction and said transistors in logic circuits (Page 4 Lines 11 to

14).

3. Claims 1, 10 and 11 are rejected under 35 U.S.C. 102(b) as being anticipated by

Phillips (WO 01/93337 and hereinafter Phillips '337).

Phillips '337 show all aspects of the instant invention (e.g. Figure 1) including a NPN

transistor 10 with a P-type material base region 21 with a base contact 24, emitter

36 and collector 16 arranged as claimed and having bandgap greater than 0.e eV

and doping level greater than 10¹⁷ cm⁻³.

(10) Response to Argument

A. Rejection of Claim 9 and 16 under 35 USC 112 (First Paragraph)

First and foremost, the Appellants' arguments concerning the rejection of Claims

9 and 16 under 35 USC 112 (first paragraph) are persuasive and this rejection has been

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dropped by the Examiner. This leaves only the rejections under 35 USC 102(b) base on the listed prior art references.

B. Rejection of Claim 1 to 9, 12 to 14 and 16 under 35 USC 102(b) anticipated by Phillips (WO 03/081674 and hereinafter Phillips '674)

The Appellants state that Phillips does not contain any disclosure of "at lest one narrow bandgap region under compressive mechanical strain" as stated in independent Claims 1 and 16. The Appellants further say that Phillips '674 does disclose any doping inherently providing compressive mechanical strain and that other parameters (such as layer thickness) can provide mechanical strain. Finally, the Appellants state that Phillips '674 teach away from the claimed invention since the structure in Phillips '674 is strain balanced i.e. no strain.

The narrow band-gap, p-doped structure in the device of Phillips '674 (region 22 as depicted in Figure 4) is identical to the instant invention (region 5 shown in Figure 1 of the instant application) in both material and thickness. The narrow band gap region in both figures is an InSb (indium antimonide) layer of about 20 nm thickness surrounded by InAlSb layers (21,23 in Phillips '674 and 4,6 in the instant application). As admitted by the instant invention (Page 3 Lines 26 to 30), compressive strain results because of the difference in lattice constant between the InAlSb/InSb layers. Therefore, the compressive strain is an inherent product of this layered structure. Phillips '674 alludes to this strain in Lines 12 to 14 on Page 10 by giving effective band gaps when strain and quantization effects are taken into consideration (Lines 21 and 22, on the same page, were listed in the Examiner's rejection to support that the p-doping of the layers, not to

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support doping as the source of compressive strain, as mistakenly interpreted by the Appellants).

As stated in MPEP 2112 (V): "ONCE A REFERENCE TEACHING PRODUCT APPEARING TO BE SUBSTANTIALLY IDENTICAL IS MADE THE BASIS OF A REJECTION, AND THE EXAMINER PRESENTS EVIDENCE OR REASONING TENDING TO SHOW INHERENCY, THE BURDEN SHIFTS TO THE APPLICANT TO SHOW AN UNOBVIOUS DIFFERENCE.". Additionally, MPEP 2112.01 (I and II) state: "WHEN THE STRUCTURE RECITED IN THE REFERENCE IS SUBSTANTIALLY IDENTICAL TO THAT OF THE CLAIMS, CLAIMED PROPERTIES OR FUNCTIONS ARE PRESUMED TO BE INHERENT" and "IF THE COMPOSITION IS PHYSICALLY THE SAME, IT MUST HAVE THE SAME PROPERTIES." In this case, the structures in Phillips '674 and the instant invention are identical structures comprising InAISb/InSb/InAISb layers. The instant invention claims that the InSb layer would have compressive stain due to its proximity to the InAISb layers. Therefore, the presence of compressive strain in the InSb layer of the Phillips '674 is inherently present as it is in the instant invention. If the Appellants insist this is not the case, they must show why the InSb layer of the instant invention has compressive strain when Phillips '694 does not.

In reference to Phillips '674 teaches away from the claimed invention by teaching a strain-balanced structure, balanced strain does not mean the absence of strain. It means that the collective strain in the layers cancel each other out. There is still strain present in layers.

C. Examiner fails to even allege that Phillips '337 (i.e. WO/01/93337 A1) contains "at lest one narrow bandgap region under compressive mechanical strain"

The Appellant states that the Examiner's rejection of Claims 1, 10 and 11 under Phillips '337 does not even allege that the device in Phillips '337 has a small band gap material under compressive mechanical strain. However, the structure shown in Figure 1 of Phillips '337 depicts the p⁺ base layer 18 made of InSb in contact with two layers 20,26 of InAlSb. As stated above and in the Specification (Page 6 Lines 9 to 11), the difference in lattice constant between the InSb/InAlSb layer imparts a compressive strain to the narrow band gap base making the presence of this strain an inherent property of the configuration. While this is not explicitly stated in the rejection, it is implied in view of the previous analysis and statements.

D. No Basis for any Future Obvious rejection using the Stated Prior Art

The Appellant's statement the any anticipated rejections based upon 35 USC 103(c) should not be considered or attempted because of previous assignment of the prior art to the inventive entity as the instant invention is premature and incorrect. Both Phillips references used in these rejections are under 35 USB 102(b) and are legitimate prior art under any circumstances.

E. and F. Failure To Establish A *Prima Facie* Case Of Anticipation

The above arguments clearly establish the legitimacy of the Examiners rejection establishing a prima facie case of anticipation by the stated prior art to the instant invention.

(11) Related Proceeding(s) Appendix

No decision rendered by a court or the Board is identified by the examiner in the Related Appeals and Interferences section of this examiner's answer.

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For the above reasons, it is believed that the rejections should be sustained.

Respectfully submitted,

/Howard Weiss/ Primary Examiner Art Unit 2814

Conferees:

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Ricky Mack /R. L. M./ Supervisory Patent Examiner, Art Unit 2873